

Spezifikationen	
Artikelnummer	MJD32C-TP
Hersteller	Micro Commercial Components (MCC)
Beschreibung	TRANS PNP 100V 3A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	2630 pcs Stock
Spannung - Kollektor-Emitter-Durchbruch (max)	100V
VCE Sättigung (Max) @ Ib, Ic	1.2V @ 375mA, 3A
Transistor-Typ	PNP
Supplier Device-Gehäuse	D-Pak
Serie	-
Leistung - max	1.25W
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Betriebstemperatur	150°C (TJ)
Befestigungsart	Surface Mount
Frequenz - Übergang	3MHz
DC Stromgewinn (HFE) (Min) @ Ic, VCE	10 @ 3A, 4V
Strom - Collector Cutoff (Max)	50µA
Strom - Kollektor (Ic) (max)	3A

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MJD32C
N/A
TRANS PNP 100V 3A D-PAK



MJD32CQ-13
Diodes Incorporated
TRANS PNP 100V 3A TO252-3L



MJD32C-13
Diodes Incorporated
TRANS PNP 100V 3A TO252-3L

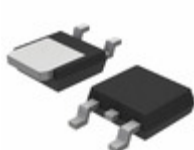


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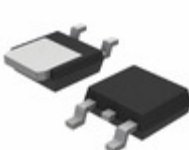
MJD32C1
ON
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MJD32C IC
PANJIT
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Mehr

Schlüsselwort				
Micro Commercial Components (MCC)	MJD32C-TP Datenblatt	MJD32C-TP-Datenblätter	MJD32C-TP PDF	Micro Commercial Components (MCC) MJD32C-TP
MJD32C-TP Electronic	MJD32C-TP-Komponenten	MJD32C-TP-Verteiler	MJD32C-TP-Bild	MJD32C-TP-Teil
MJD32C-TP Preis	MJD32C-TP Hersteller	MJD32C-TP Bild	MJD32C-TP Aktie	MJD32C-TP Inventar
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